

## S5D05170H

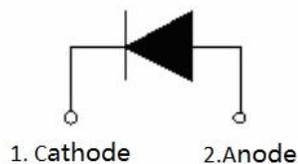
### 1700V SIC POWER SCHOTTKY RECTIFIERS



#### Description

This 1700V 5A diode is high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S5D05170H is ideal for energy sensitive, high frequency applications in challenging environments.

#### Circuit Diagram



#### Features

- 175°C TJ operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

#### Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

## Maximum Ratings

| Characteristics  | Symbol                          | Condition   | Max. | Units |
|--|---------------------------------|---|------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | -   | 1700 | V     |
| Average Rectified Forward Current  | $I_{F(AV)1}$                    | $T_c=25^{\circ}\text{C}$                            | 23   | A     |
|  | $I_{F(AV)2}$                    | $T_c=158^{\circ}\text{C}$                           | 5    | A     |
| Peak One Cycle Non-Repetitive Surge Current  | $I_{FSM1}$                      | 10ms, Half Sine pulse, $T_c=25^{\circ}\text{C}$     | 115  | A     |
|  | $I_{FSM2}$                      | 10ms, Half Sine pulse, $T_c=110^{\circ}\text{C}$    | 105  | A     |
| Repetitive Peak Forward Surge Current  | $I_{FRM1}$                      | 10 ms, Half Sine pulse, $T_c=25^{\circ}\text{C}$    | 69   | A     |
|  | $I_{FRM2}$                      | 10 ms, Half Sine pulse, $T_c=110^{\circ}\text{C}$   | 63   | A     |
| Non-Repetitive Peak Forward Surge Current  | $I_{F,Max1}$                    | 10 $\mu\text{s}$ . Pulse, $T_c=25^{\circ}\text{C}$  | 200  | A     |
|  | $I_{F,Max2}$                    | 10 $\mu\text{s}$ . Pulse, $T_c=110^{\circ}\text{C}$ | 160  | A     |
| Power Dissipation  | $P_{tot1}$                      | $T_c=25^{\circ}\text{C}$                            | 187  | W     |
|  | $P_{tot2}$                      | $T_c=110^{\circ}\text{C}$                           | 81   | W     |

## Electrical Characteristics:

| Characteristics           | Symbol   | Condition  | Typ.  | Max. | Units         |
|---------------------------|----------|--|-------|------|---------------|
| Forward Voltage Drop*     | $V_{F1}$ | @ 5A, Pulse, $T_j = 25^{\circ}\text{C}$  | 1.5   | 1.8  | V             |
|                           | $V_{F2}$ | @ 5A, Pulse, $T_j = 175^{\circ}\text{C}$   | 2.4   | 2.6  | V             |
| Reverse Current*          | $I_{R1}$ | @ $V_R = \text{rated } V_R, T_j = 25^{\circ}\text{C}$  | 1     | 10   | $\mu\text{A}$ |
|                           | $I_{R2}$ | @ $V_R = \text{rated } V_R, T_j = 175^{\circ}\text{C}$   | 10    | 100  | $\mu\text{A}$ |
| Junction Capacitance      | $C_{T1}$ | $V_R=0\text{V}, f=1\text{MHz}, T_j=25^{\circ}\text{C}$   | 497   | -    | pF            |
|                           | $C_{T2}$ | $V_R=1700\text{V}, f=1\text{MHz}, T_j=25^{\circ}\text{C}$ ,  | 28.6  | -    | pF            |
| Reverse Recovery Charge   | $Q_c$    | $I_F = 5\text{A}, di/dt = 200\text{A}/\mu\text{s}$<br>$V_R = 1700\text{V}, T_j = 25^{\circ}\text{C}$ | 65.84 | -    | nC            |
| Capacitance Stored Energy | $E_c$    | $V_R = 1700\text{V}, T_j = 25^{\circ}\text{C}$   | 67.91 | -    | $\mu\text{J}$ |

\* Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

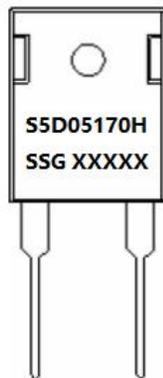
## Thermal-Mechanical Specifications:

| Characteristics                             | Symbol          | Condition    | Specification | Units |
|---|-----------------|--------------|---------------|-------|
| Junction Temperature                        | $T_j$           | -            | -55 to +175   | °C    |
| Storage Temperature                         | $T_{stg}$       | -            | -55 to +175   | °C    |
| Typical Thermal Resistance Junction to Case | $R_{\theta JC}$ | DC operation | 0.8           | °C/W  |

## Ordering Information

| Device    | Package            | Shipping     |
|-----------|--------------------|--------------|
| S5D05170H | TO-247AC(TO-247-2) | 25pcs / tube |

## Marking Diagram

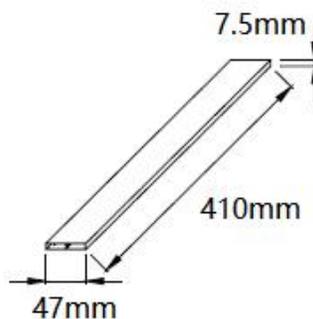


Where XXXXX is YYWWL

S5D = Device Type  
 H = Package type  
 05 = Forward Current (5A)  
 170 = Reverse Voltage (1700V)  
 SSG = SSG  
 YY = Year  
 WW = Week  
 L = Lot Number

**Cautions:** Molding resin  
 Epoxy resin UL94V-0

## Tube Specification



**Ratings and Characteristics Curves**

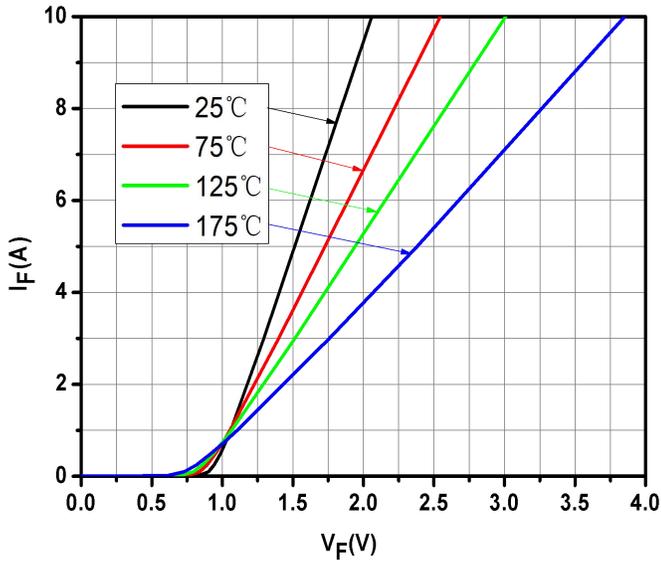


Fig.1-Typical Forward Voltage Characteristics

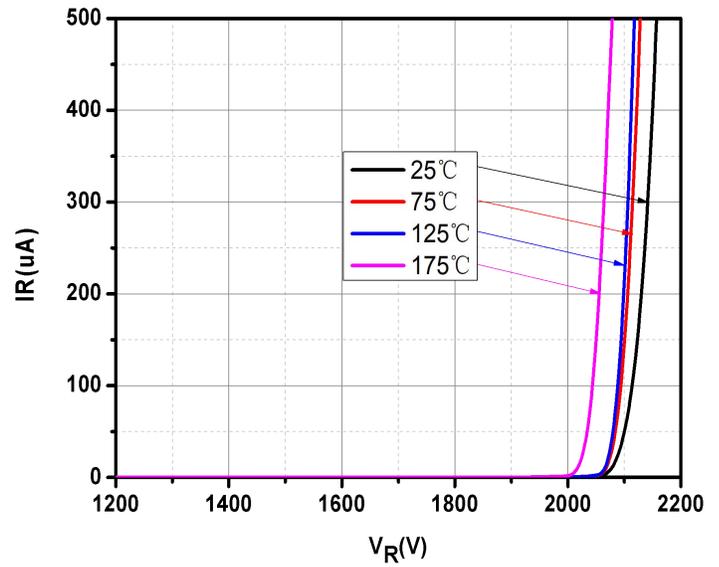


Fig.2-Typical Reverse Characteristics

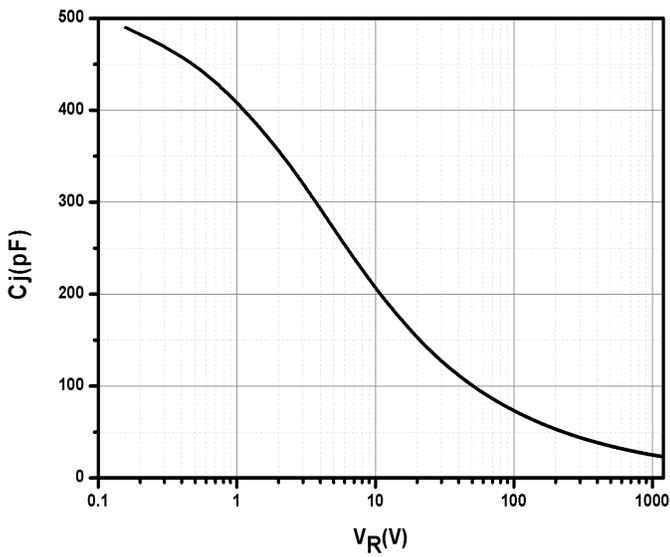


Fig.3-Capacitance vs. Reverse Voltage

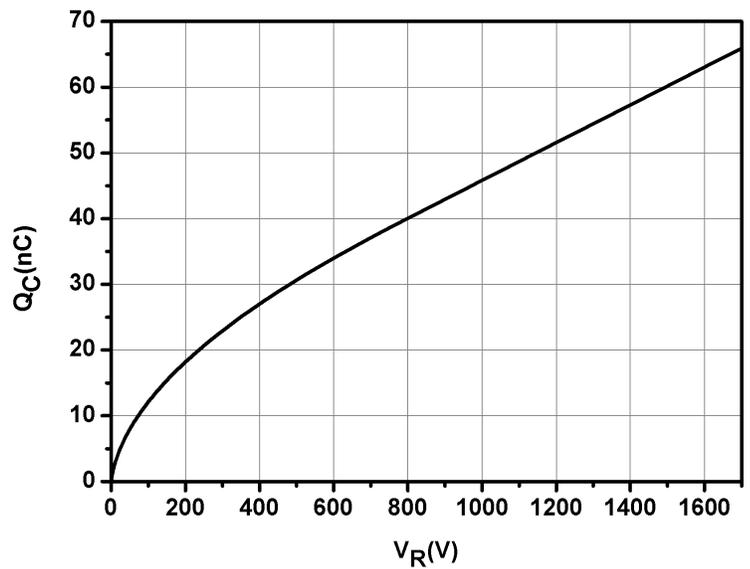


Fig.4-Total Capacitance Charge vs. Reverse Voltage

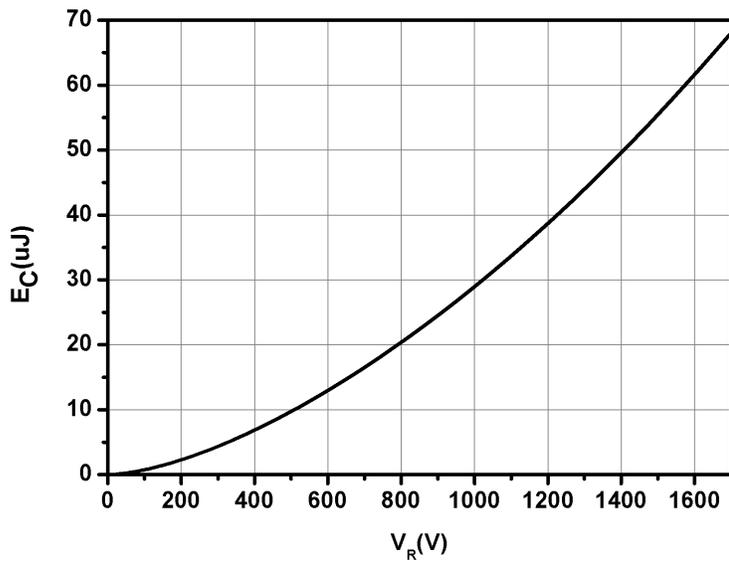


Fig.5-Capacitance Stored Energy

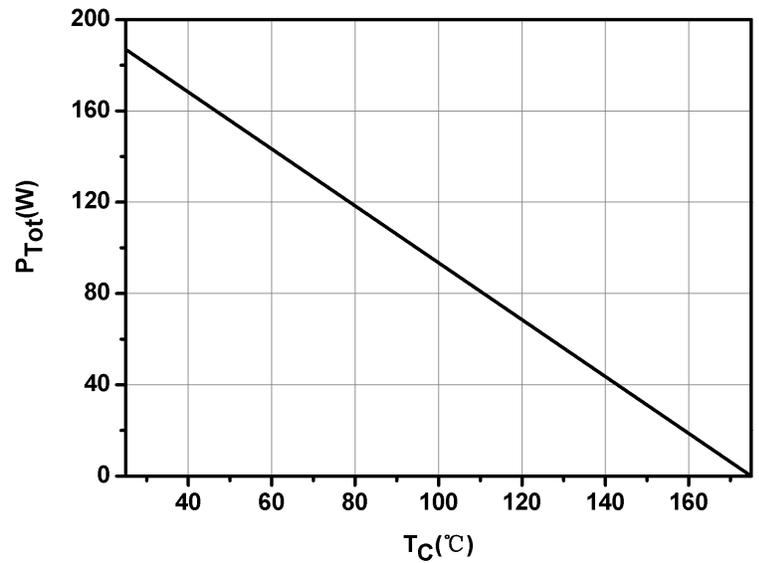


Fig.7-Power Derating

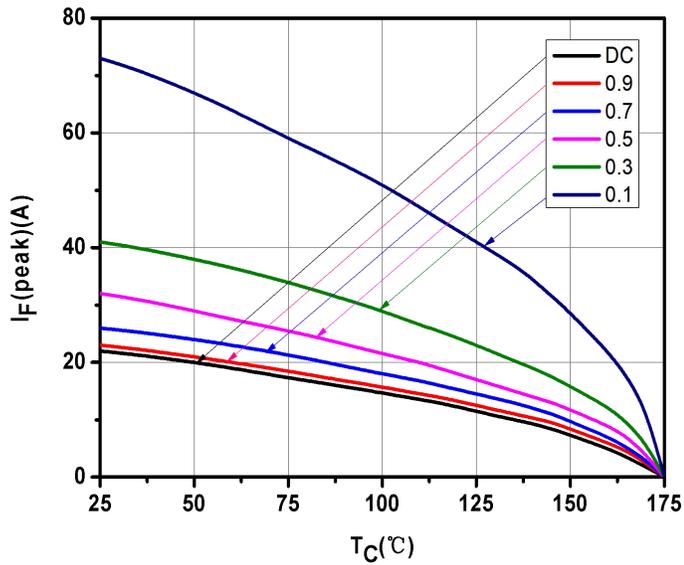
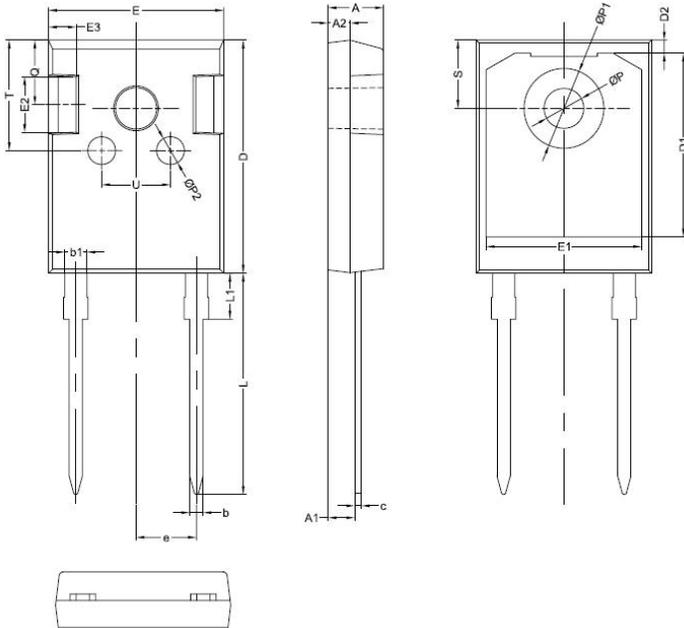


Fig.8-Current Derating

## Mechanical Dimensions TO-247AC(TO-247-2)



| SYMBOL | Millimeters |       |       |
|--------|-------------|-------|-------|
|        | MIN.        | TYP.  | MAX.  |
| A      | 4.80        | 5.00  | 5.20  |
| A1     | 2.20        | 2.41  | 2.61  |
| A2     | 1.90        | 2.00  | 2.10  |
| b      | 1.10        | 1.20  | 1.35  |
| b1     | 1.80        | 2.00  | 2.20  |
| c      | 0.50        | 0.60  | 0.75  |
| D      | 20.30       | 21.00 | 21.20 |
| D1     |             | 16.58 |       |
| D2     |             | 1.17  |       |
| E      | 15.60       | 15.80 | 16.00 |
| E1     |             | 14.02 |       |
| E2     |             | 5.00  |       |
| E3     |             | 2.50  |       |
| e      |             | 5.44  |       |
| L      | 19.42       | 19.92 | 20.42 |
| L1     |             | 4.13  |       |
| P      | 3.50        | 3.60  | 3.70  |
| P1     | 7.1         | 7.19  | 7.40  |
| P2     |             | 2.50  |       |
| Q      |             | 5.80  |       |
| S      | 6.05        | 6.15  | 6.25  |
| T      |             | 10.00 |       |
| U      |             | 6.20  |       |

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